

2.0A FAST RECOVERY RECTIFIER BRIDGE
RECTIFIER Reverse Voltage –1000 V
Forward Current – 2.0A

FEATURES

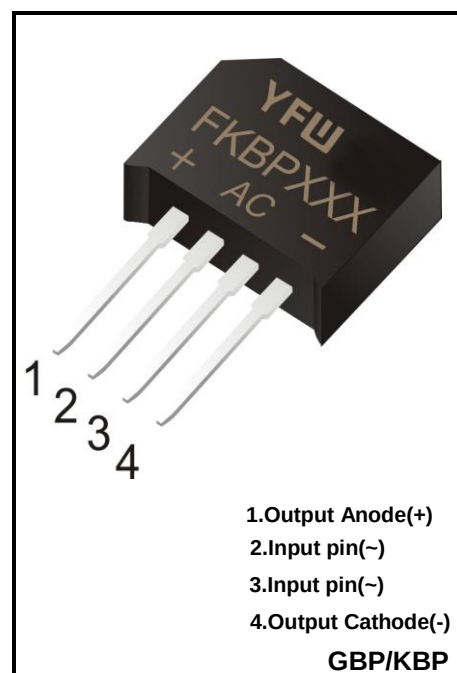
- ♦Ultrasonic recovery
- ♦LOW I_{RRM} , LOW V_F , LOW V_{RRM}
- ♦Glass Passivated Chip Junction
- ♦Special frame design for heat dissipation
- ♦Lead free in comply with EU RoHS 2011/65/EU directives

BENEFITS

- ♦Reduced EMI
- ♦Reduced Power loss and switching transistor
- ♦Reduced snubbing

MECHANICAL DATA

- ♦Case: GBP/KBP
- ♦Terminals: Solderable per MIL-STD-750, Method 2026



Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

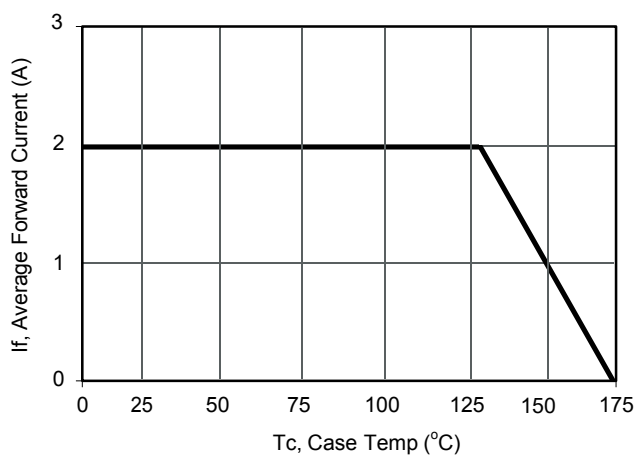
Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	FKBP210	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	1000	V
Maximum RMS voltage	V_{RMS}	700	V
Maximum DC Blocking Voltage	V_{DC}	1000	V
Average Rectified Output Current	I_o	2.0	A
Reverse Recovery Time. $I_F=0.5A, I_R=1A, I_{RR}=0.25A$	T_{rr}	500	nS
Peak Forward Surge Current 8.3 ms Single Half Sine-Wave Superimposed on Rated Load(JEDEC method)	I_{FSM}	55	A
I^2t Rating for Fusing($1ms \leq t \leq 10ms$)	I^2t	15	A ² S
Maximum Forward Voltage at 1.0 A	V_F	1.0	V
Maximum DC Reverse Current at Rated DC Blocking Voltage @ $T_A=25^\circ C$ @ $T_A=125^\circ C$	I_R	5 100	uA
Typical Junction Capacitance (Note1)	C_j	40	pF
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +175	°C

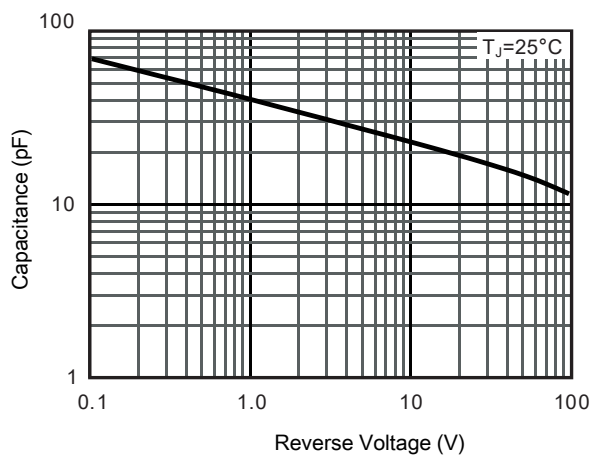
Note: 1. Measured at 1MHz and applied reverse voltage of 4 V D.C.

2. Mounted on glass epoxy PC board with 4×1.5"×1.5" (3.81×3.81 cm) copper pad.

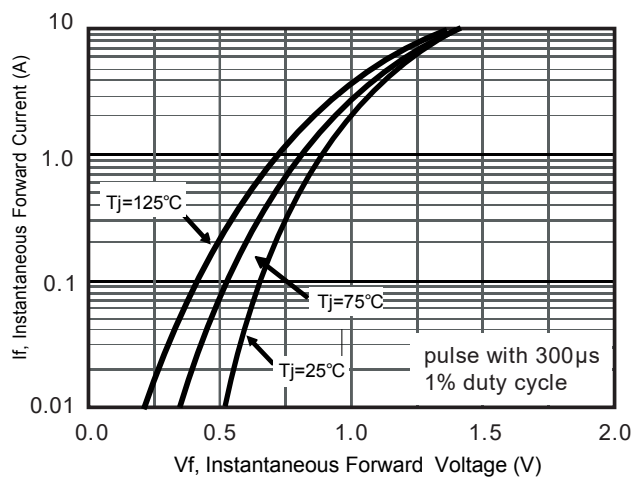
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25^\circ\text{C}$ unless otherwise noted)



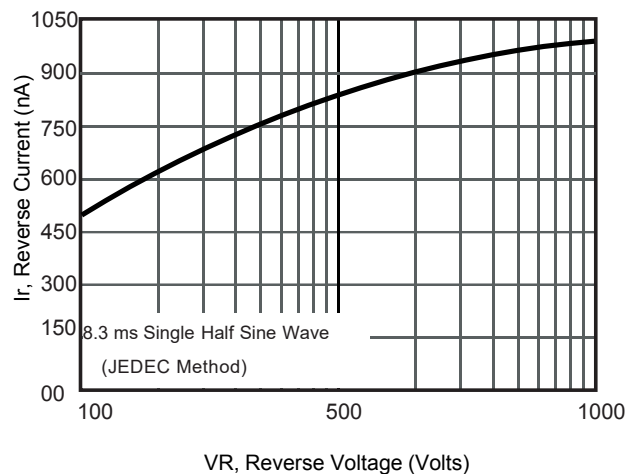
Current Derating, Case



Typical Junction Capacitance

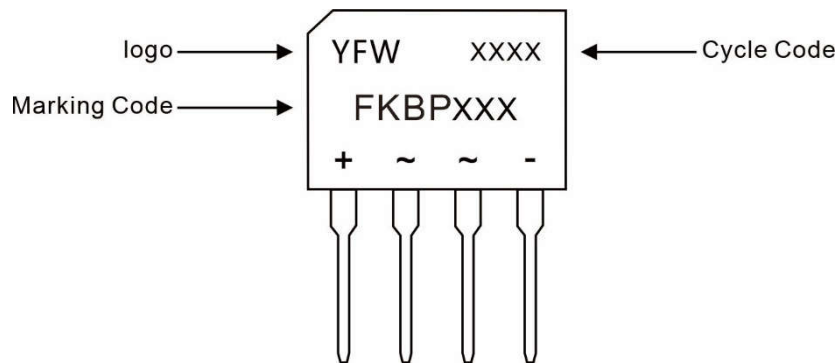


Typical Forward Voltage



Typical Reverse Current

Marking Diagram



Ordering information

Package	Packing Description	Packing Quantity
KBP	bulk	500PCS/Box 5000PCS/Carton

Package Dimensions

KBP

Dim.	Millimeter(mm)		Dimensions inInch	
	Min.	Max.	Min.	Max.
A	14.3	14.60	0.56	0.57
B	3.0	3.3	0.12	0.13
c	10.45	10.75	0.41	0.42
D	14.41	14.71	0.57	0.58
d	1.40	1.70	0.06	0.07
E	2.0	2.30	0.09	0.09
F	0.90	1.20	0.04	0.05
G	3.50	3.80	0.14	0.15
H	0.35	0.37	0.01	0.01
I	1.43	1.45	0.06	0.06
J	0.8	0.83	0.03	0.03
K	2.7×45° (Typ)		0.11×45° (Typ)	
L	#	3°	#	3°
M	#	2°	#	2°

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